



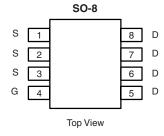
# N-Channel Reduced $Q_g$ , Fast Switching MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
30	0.0185 at V <sub>GS</sub> = 10 V	9		
	0.030 at V <sub>GS</sub> = 4.5 V	7		

### **FEATURES**

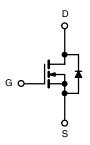
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET
- High-Efficient PWM Optimized
- 100 % UIS and R<sub>g</sub> Tested





Ordering Information: Si4800BDY-T1-E3 (Lead (Pb)-free)

Si4800BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> T	$_{A}$ = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	30		V
Gate-Source Voltage		V <sub>GS</sub>	± 25		
Continuous Drain Current /T 150 °C\â.b	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	9	6.5	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 70 °C		7.0	5.0	
Pulsed Drain Current (10 µs Pulse Width)		I <sub>DM</sub>	40		Α
Continuous Source Current (Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	2.3		
Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	15		
Single-Pulse Avalanche Energy	L=0.1 IIII	E <sub>AS</sub>	11.25		mJ
Mariana Barra Biraira da h	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.5 1.3		W
Maximum Power Dissipation <sup>a, b</sup>	T <sub>A</sub> = 70 °C	1 'D	1.6	0.8	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
			Limits		
Parameter		Symbol	Тур.	Max.	Unit
Manipana lumation to Ambienti	t ≤ 10 s	R <sub>thJA</sub>	40	50	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' ¹thJA	70	95	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	24	30	

Notes

a. Surface Mounted on FR4 board.

b.  $t \le 10 \text{ s}$ .

# Si4800BDY

# Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	<u>'</u>				l l		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.8		1.8	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zana Cata Valtana Busin Commant		V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V		1			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
	В	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 9 A		0.0155	0.0185		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 7 \text{ A}$		0.023	0.030	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 9 A		16		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V	
Dynamic <sup>b</sup>	'			•			
Total Gate Charge	Qg			8.7	13		
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 5.0 V, I <sub>D</sub> = 9 A		1.5		nC	
Gate-Drain Charge	$Q_{gd}$			3.5			
Gate Resistance	$R_g$		0.5	1.4	2.2	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			7	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		12	20		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 10 V, $R_g$ = 6 $\Omega$		32	50	ns	
Fall Time	t <sub>f</sub>			14	25		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.3 A, dI/dt = 100 A/μs		30	60		

### Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

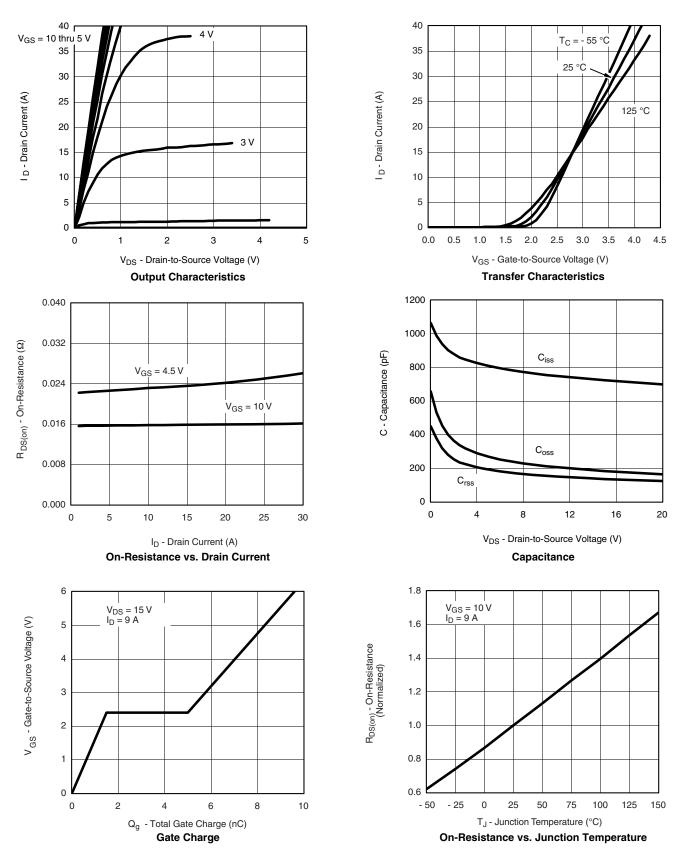
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.



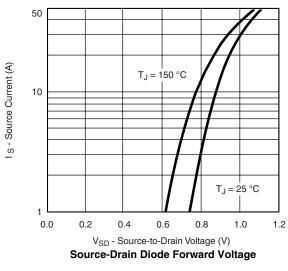


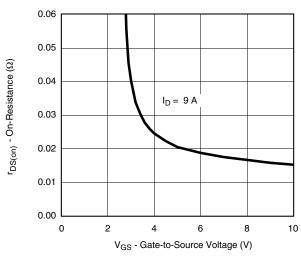
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

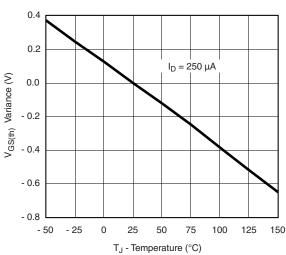


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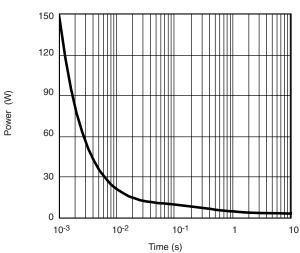
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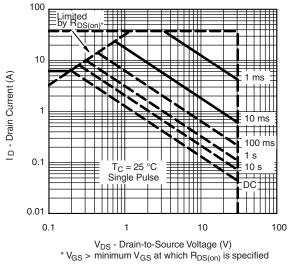


On-Resistance vs. Gate-to-Source Voltage



**Threshold Voltage** 

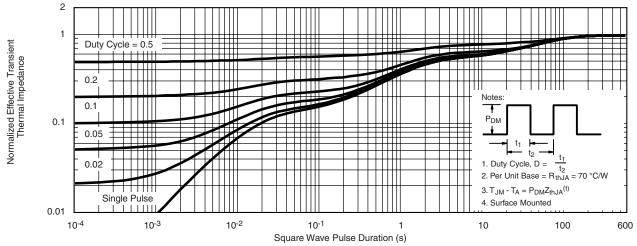
Single Pulse Power, Junction-to-Ambient



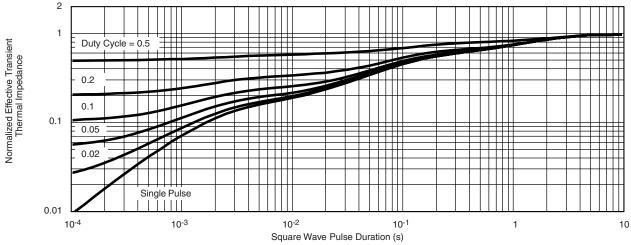
Safe Operating Area, Junction-to-Ambient



### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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Document Number: 72124 S-83039-Rev. H, 29-Dec-08



SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INC	HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

DWG: 5498

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### **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)

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